
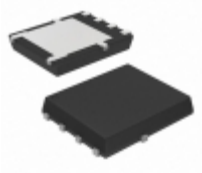
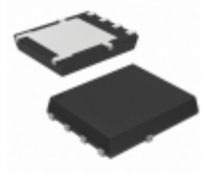
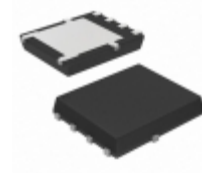
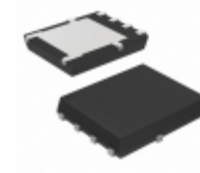

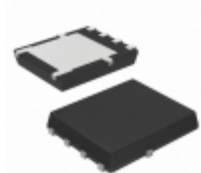
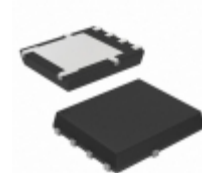
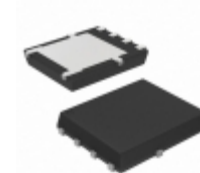
	<h2 style="color: red;">NTMFS4119NT3G</h2>
	<p>Hersteller-Teilenummer: NTMFS4119NT3G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 11A SO8FL</p> <p>Datenblätter:  NTMFS4119NT3G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMFS4119NT3G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 11A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	4000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	900mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11A (Ta)
Rds On (Max) @ Id, Vgs	3.5 mOhm @ 29A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	4800pF @ 24V
Verpackung	Tape & Reel (TR)

NTMFS4119NT3G ist neu im Original, Suche NTMFS4119NT3G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4119NT3G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4119NT3G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMFS4120NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>	 <p>NTMFS4119NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>	 <p>NTMFS4108NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 13.5A SO8FL</p>	 <p>NTMFS4122NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.1A SO-8FL</p>
 <p>NTMFS4119NT ON NTMFS4119NT ON</p>	 <p>NTMFS4108NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 13.5A SO-8FL</p>	 <p>NTMFS4121NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>	 <p>NTMFS4120NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>

heiße Teile

Mehr

NTMD5838NL	NTMD5838NLR2G	NTMD6N02	NTMD6N02DR2G	NTMD6N02R2G
NTMD6N03	NTMD6N03DR2G	NTMD6N03R2	NTMD6N03R2G	NTMD6N04
NTMD6N04R2G	NTMD6P02	NTMD6P02R2	NTMD6P02R2G	NTMD6P02R2G.
NTMD6P02R2SG	NTMFD4901NF1G	NTMFD4901NFT1G	NTMFD4902NF1G	NTMFD4902NFT1G
NTMFD4C85NT1G	NTMFD4C85NTG	NTMFD4H089NFT1G	NTMFS4108NT1G	NTMFS4108NT3G
NTMFS4120NT1G	NTMFS4121NT1G	NTMFS4701NT1G	NTMFS4707NT1G	NTMFS4708NT1G
NTMFS4709NT1G	NTMFS4709NT3G	NTMFS4744NT1G	NTMFS4821NT1G	NTMFS4823NT1G
NTMFS4833NT1G	NTMFS4834N	NTMFS4834NT1G	NTMFS4835N	NTMFS4835NT1G
NTMFS4837NHT1G	NTMFS4837NHT3G	NTMFS4837NT1G	NTMFS4839NHT1G	NTMFS4841NHT1G
NTMFS4841NHT3G	NTMFS4841NT1G	NTMFS4845NT1G	NTMFS4846	NTMFS4846NT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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